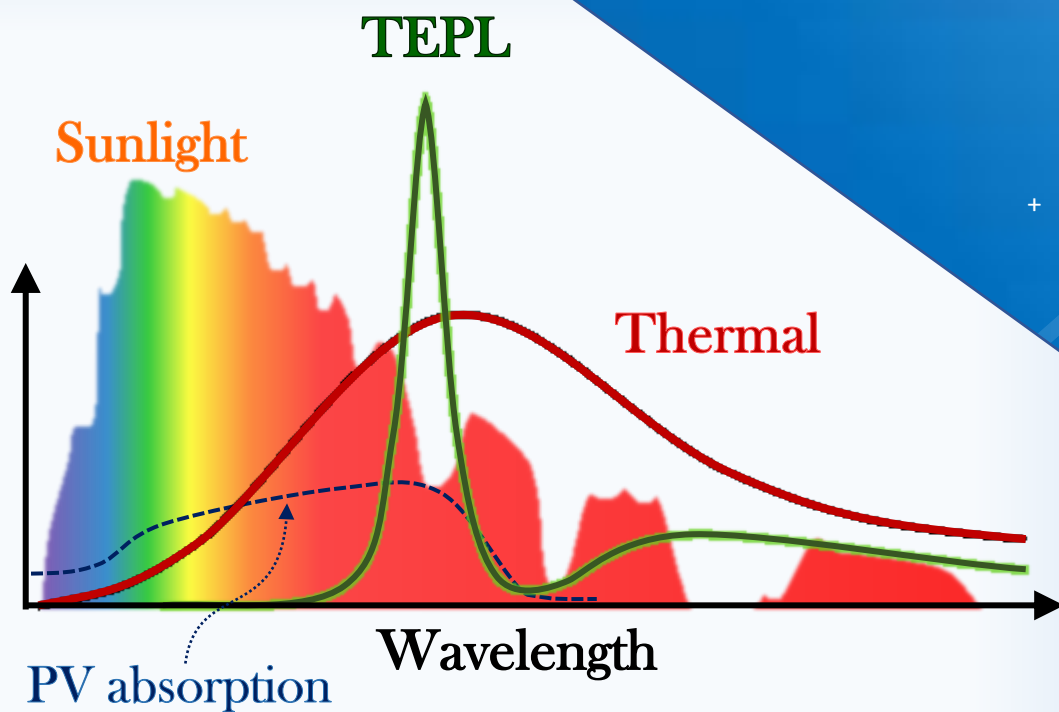
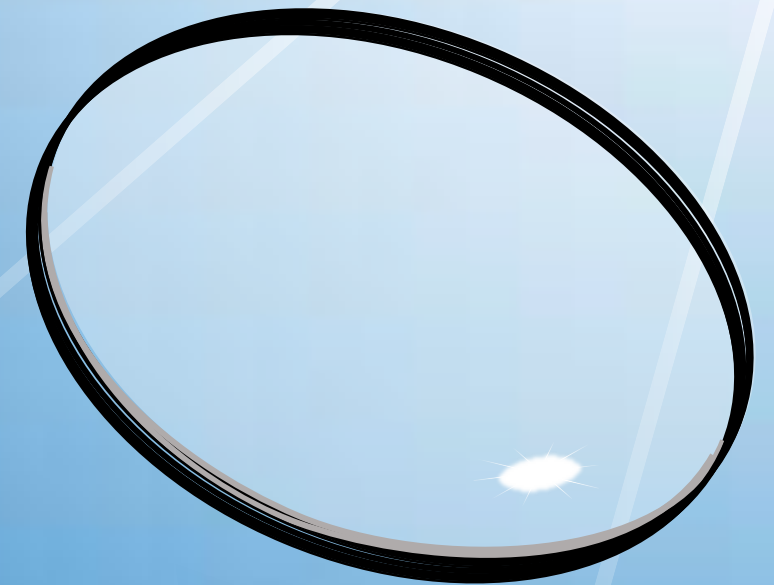




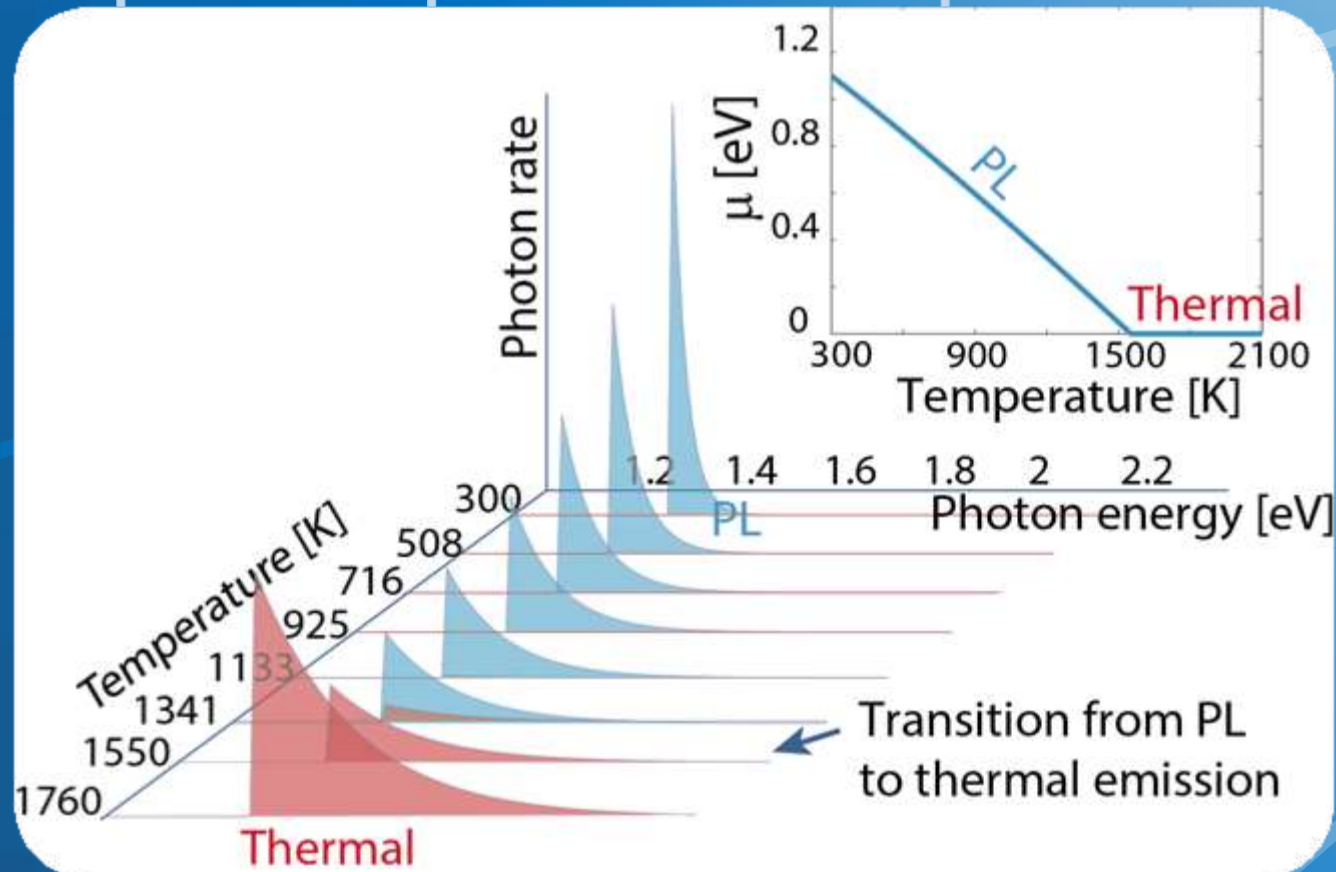
# Thermally Enhanced Photo-Luminescence Device for Solar Energy Under Practical Conditions



Nimrod  
Kruger

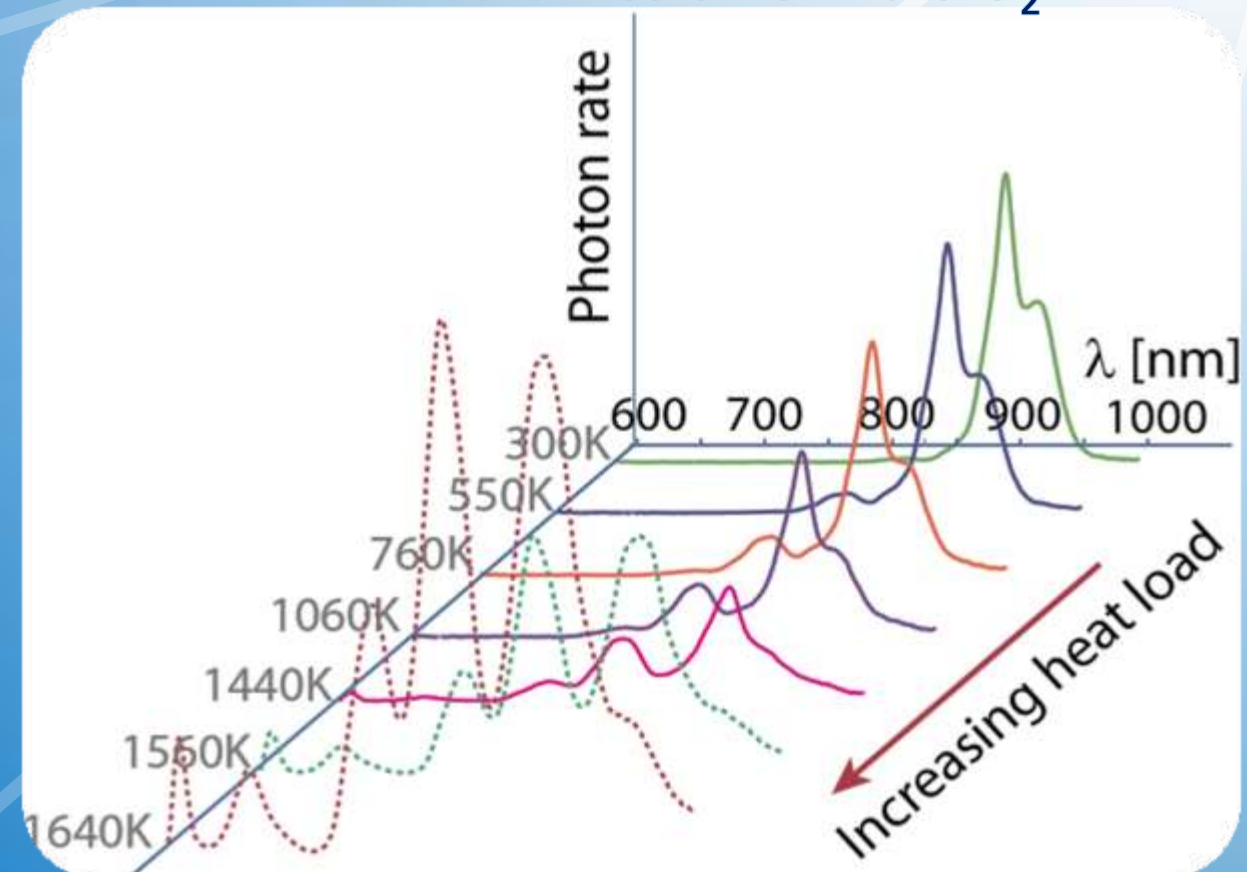
# Thermally Enhanced Photo-Luminescence (TEPL)

Temperature dependent emission spectrum model



Manor et al, *Optica* 2, 585-588 (2015)

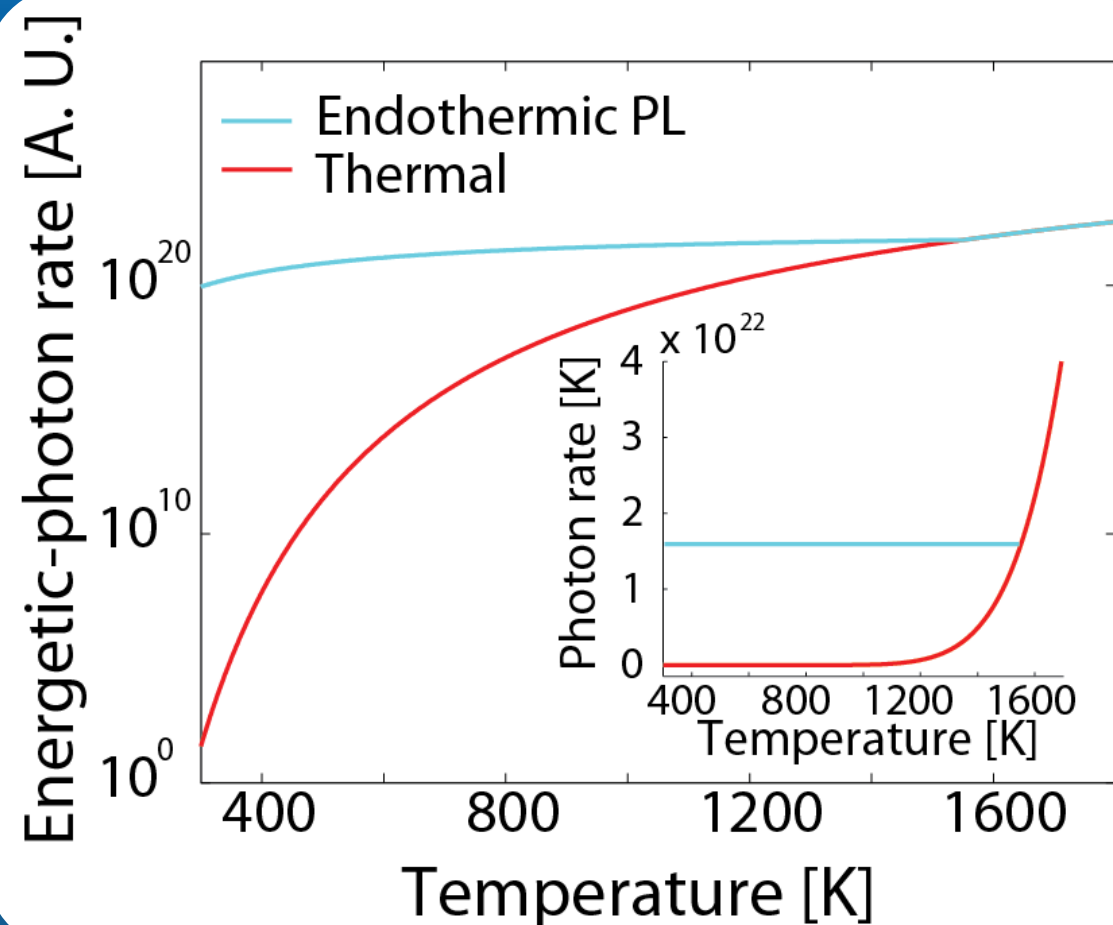
Measured emission of Nd:SiO<sub>2</sub>



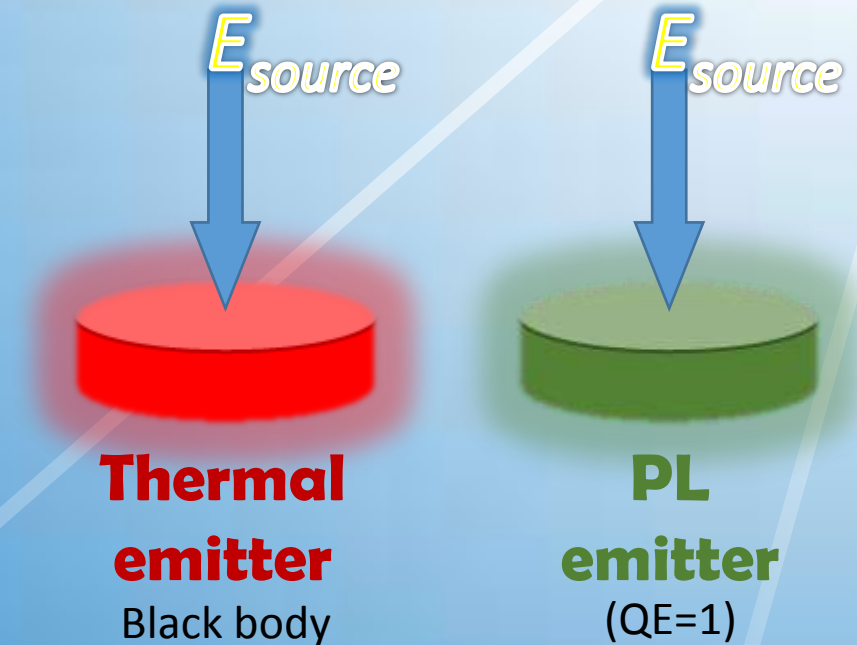
$$R(\hbar\omega, T, \mu) = \varepsilon(\hbar\omega) \cdot \frac{(\hbar\omega)^2}{4\pi^2 \hbar^3 c^2} \frac{1}{e^{\frac{\hbar\omega - \mu}{K_B T}} - 1} \cong \underbrace{\varepsilon(\hbar\omega) \cdot R_0}_{\text{Thermal}} \cdot \underbrace{e^{\frac{\mu}{K_B T}}}_{\text{PL}}$$

# Thermally Enhanced Photo-Luminescence (TEPL)

Modeled number of photons with  $E_{ph} > 1.4eV$



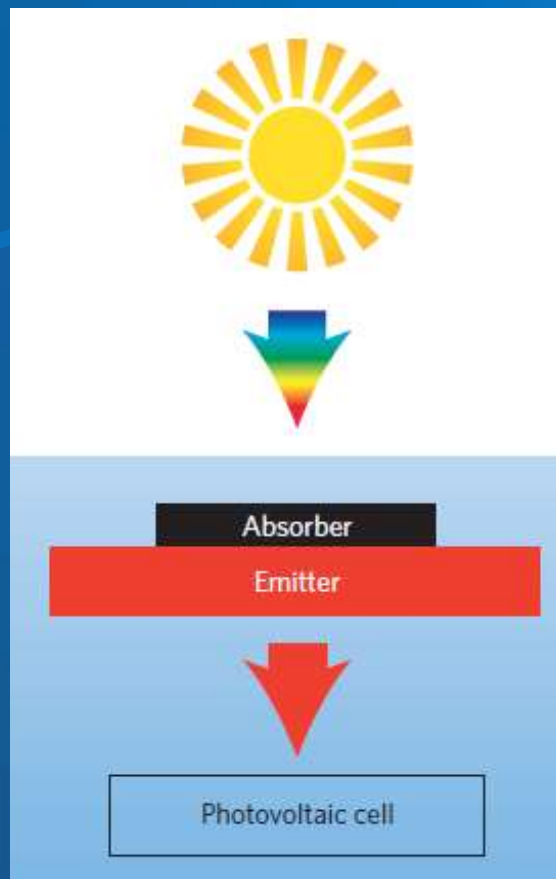
Manor et al, *Optica* 2, 585-588 (2015)



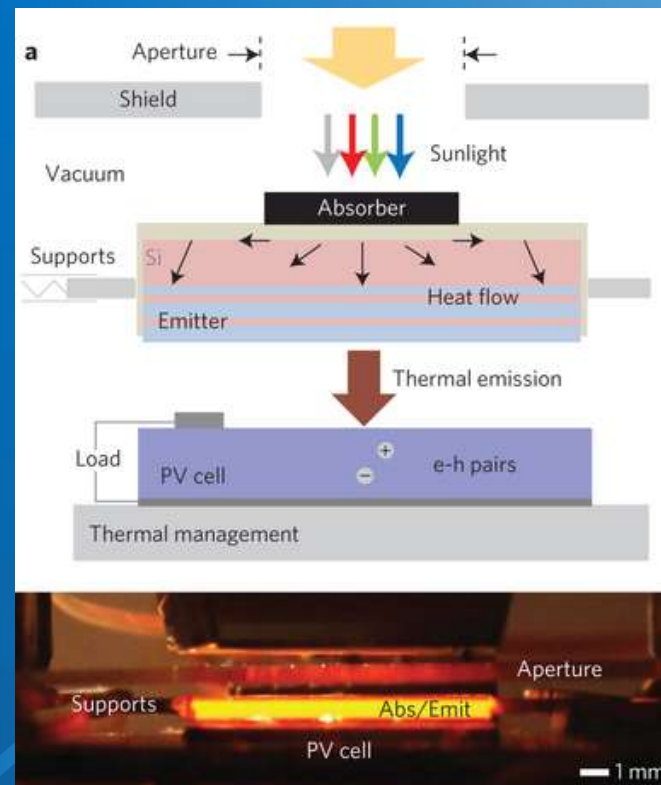
How can this be used as a device?

# Our competition: Solar-Thermal Photovoltaics

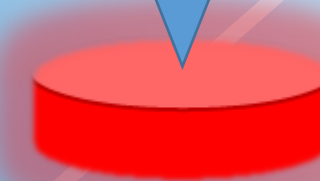
## STPV



S. Fan, Nature Nanotechnology 9, 92-93 (2014)



Lenert et al, Nature Nanotechnology 9, 126-130 (2014)

 $E_{source}$ 


**Thermal  
emitter**  
Black body

 $E_{source}$ 


**PL  
emitter**  
(QE=1)

3.2% efficiency  
for 0.55eV band-gap  
at over 1200K

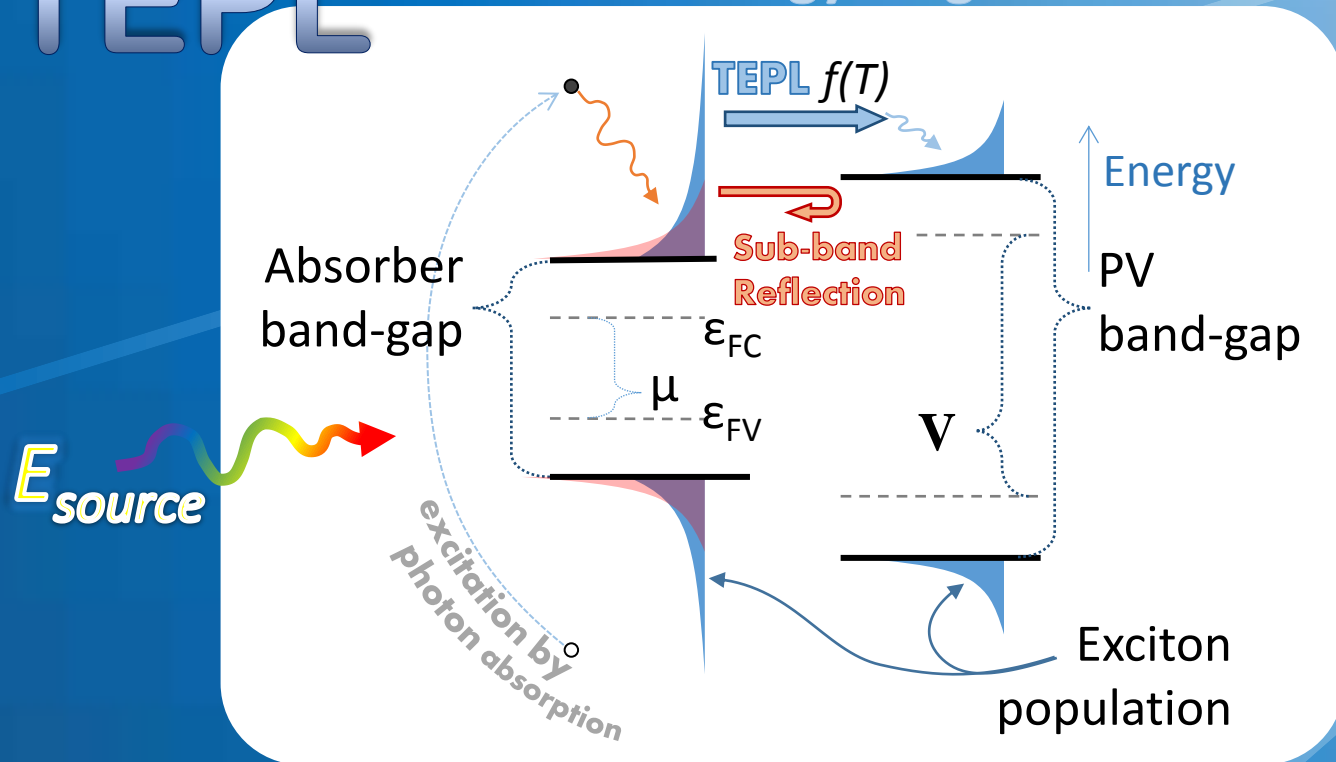
According to Wien's law:  

$$T_{opt} = 2336 \left[ \frac{K}{eV} \right] \cdot E_g$$

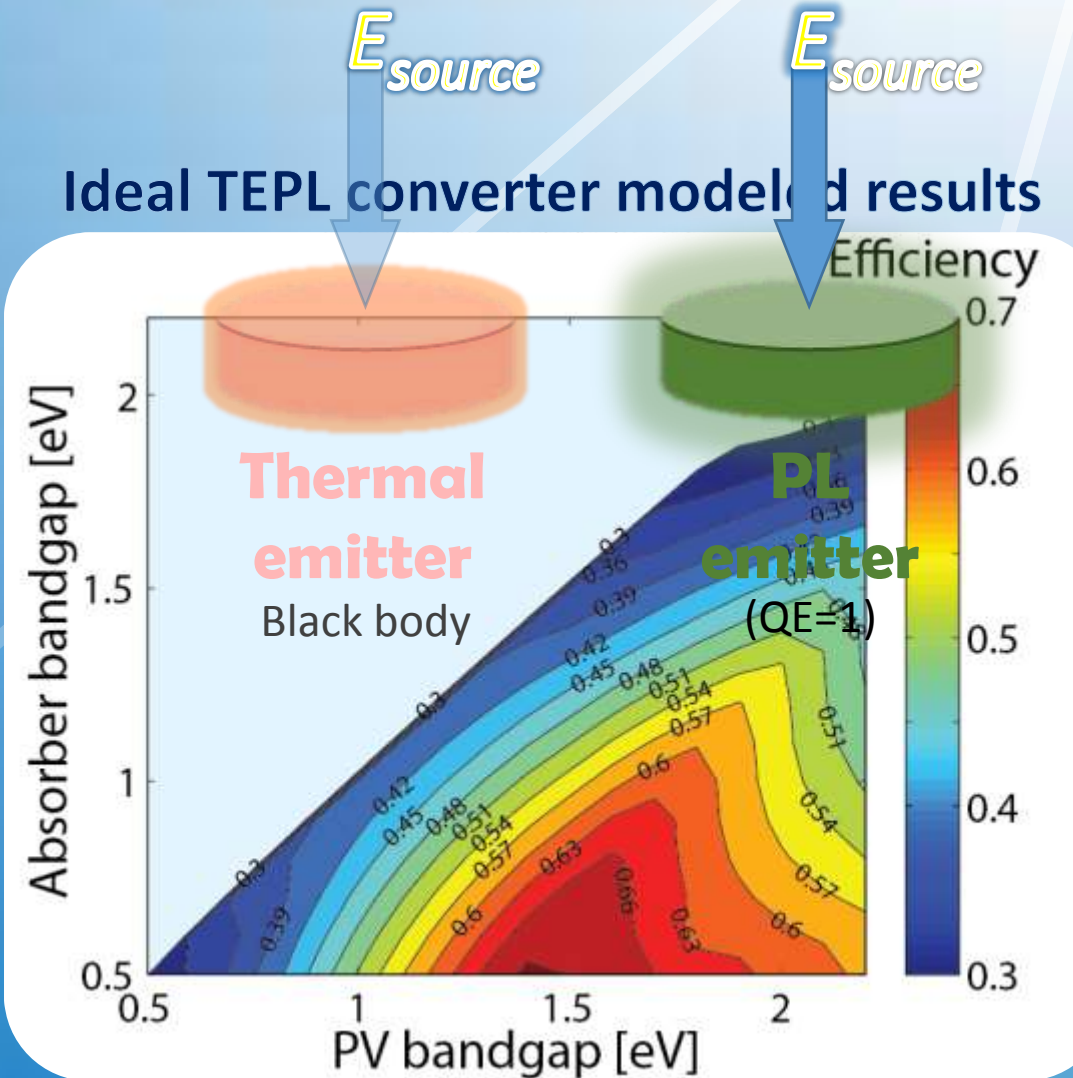
# TEPL Solar Converter: Ideal Device

## TEPL

### TEPL Energy diagram



### Ideal TEPL converter modeled results



Manor et al, Nat. Comm., Accepted (2016)

Absorber:

$$X \cdot \Omega_{sun} \cdot \int_{E_{g,Abs}}^{\infty} \overbrace{R_{sun,AM1.5} d\hbar\omega}^{\text{from sun}} + (2\pi - X \cdot \Omega_{sun}) \int_{E_{g,PV}}^{\infty} \overbrace{R_{PV}(300, V) d\hbar\omega}^{\text{from PV}} =$$

$$(2\pi - X \cdot \Omega_{sun}) \int_{E_{g,PV}}^{\infty} \overbrace{R_{abs}(T, \mu) d\hbar\omega}^{\text{to PV (above-band)}} + X \cdot \Omega_{sun} \cdot \int_{E_{g,Abs}}^{\infty} \overbrace{R_{abs}(T, \mu) d\hbar\omega}^{\text{to sun}}$$

PV:

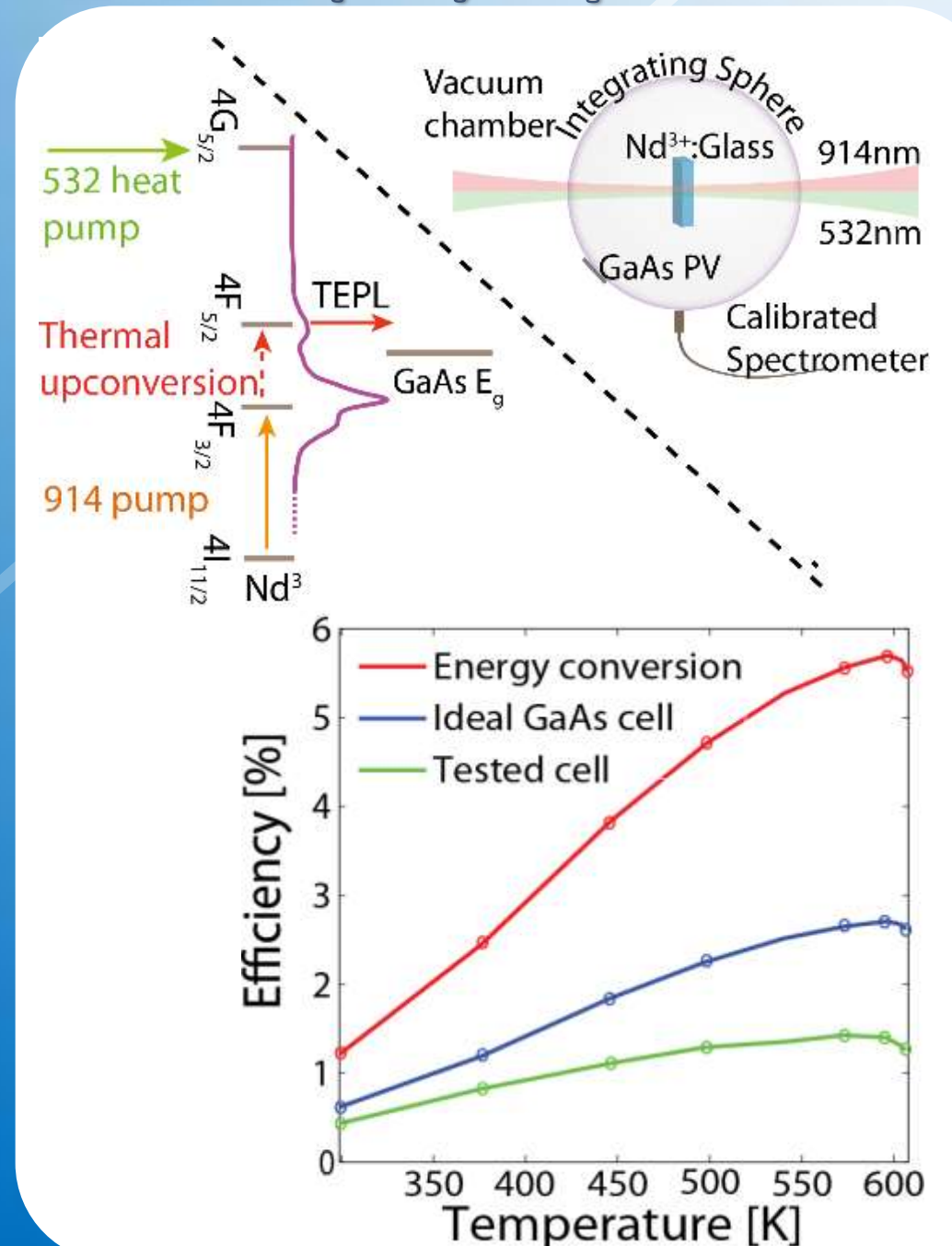
$$(2\pi - X \cdot \Omega_{sun}) \cdot \int_{E_{g,PV}}^{\infty} \overbrace{R_{abs}(T, \mu) d\hbar\omega}^{\text{from absorber}} = (2\pi - X \cdot \Omega_{sun}) \cdot \int_{E_{g,PV}}^{\infty} \overbrace{R_{PV}(300, V) d\hbar\omega}^{\text{to absorber}} + \frac{I}{e}$$

# TEPL Solar Converter: Proof of concept



Grand Technion  
Energy Program  
תוכנית האנרגיה ע"ש גרנד

## Up-Conversion (UC) experiment:



## State of the art thermal UC:

ARTICLE

Received 30 May 2014 | Accepted 27 Oct 2014 | Published 28 Nov 2014

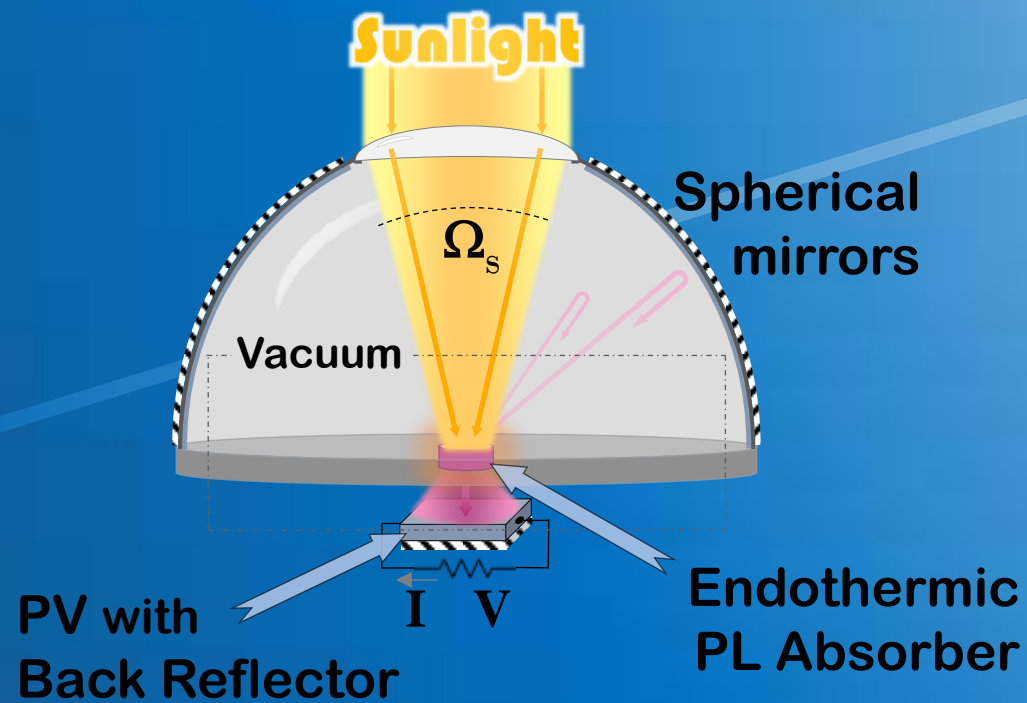
DOI: 10.1038/ncomms6669

Photon energy upconversion through thermal radiation with the power efficiency reaching 16%

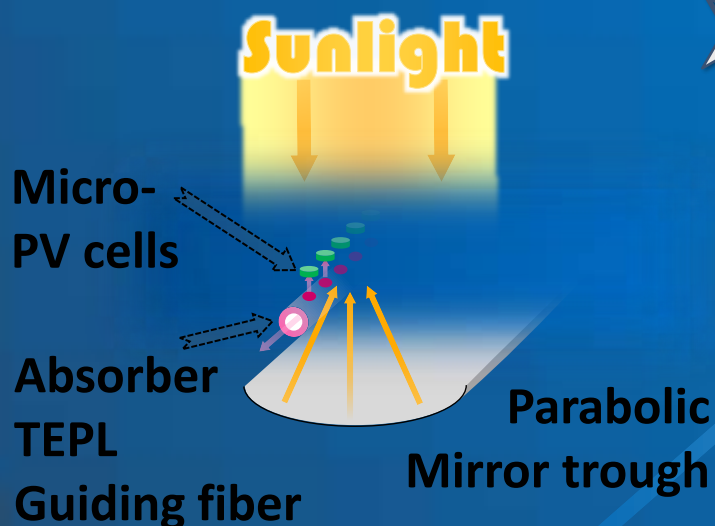
**16% at 2900K**

**But at 600K would yield 10<sup>-5</sup>%!**

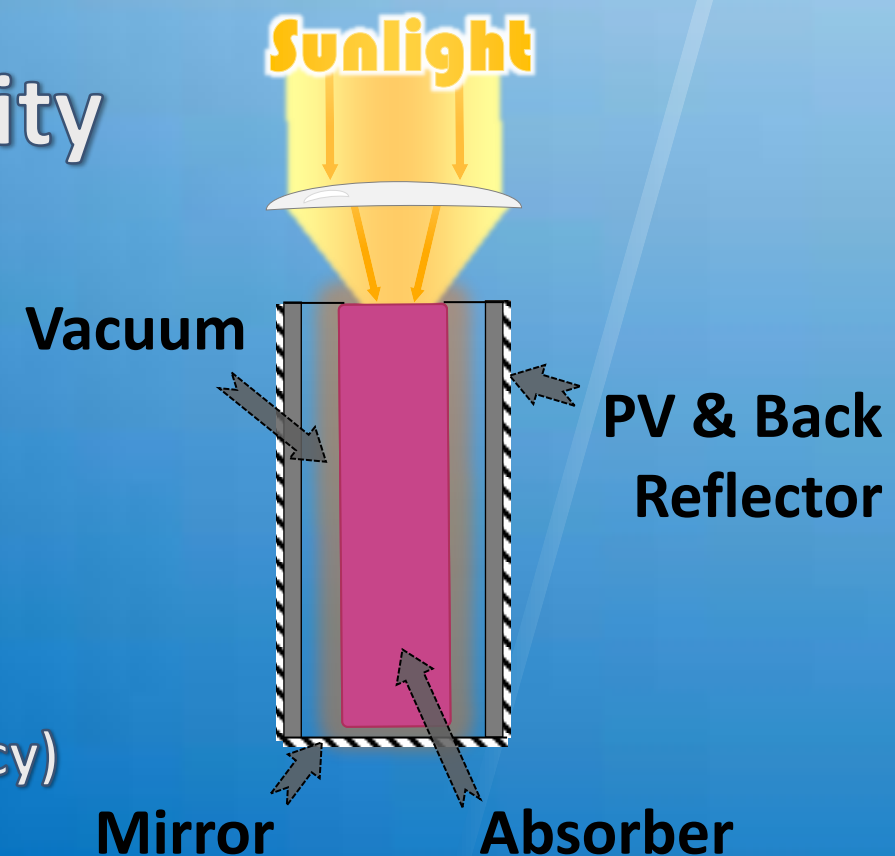
# TEPL Solar Converter: Practical considerations



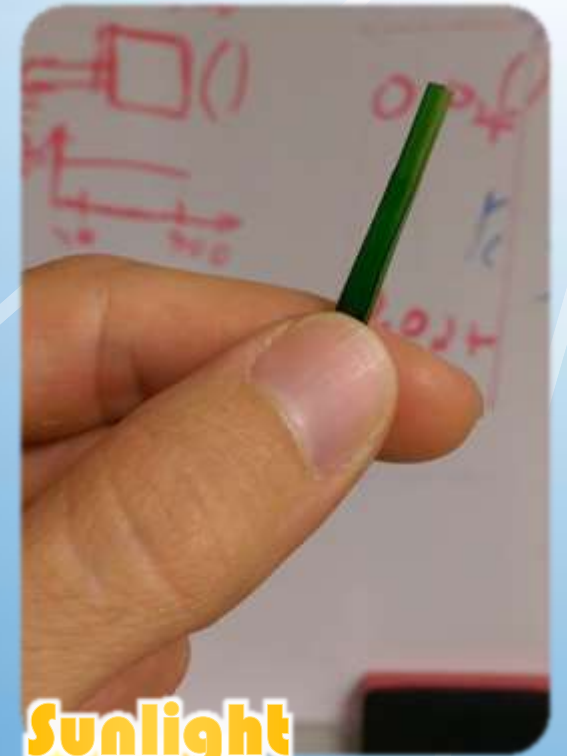
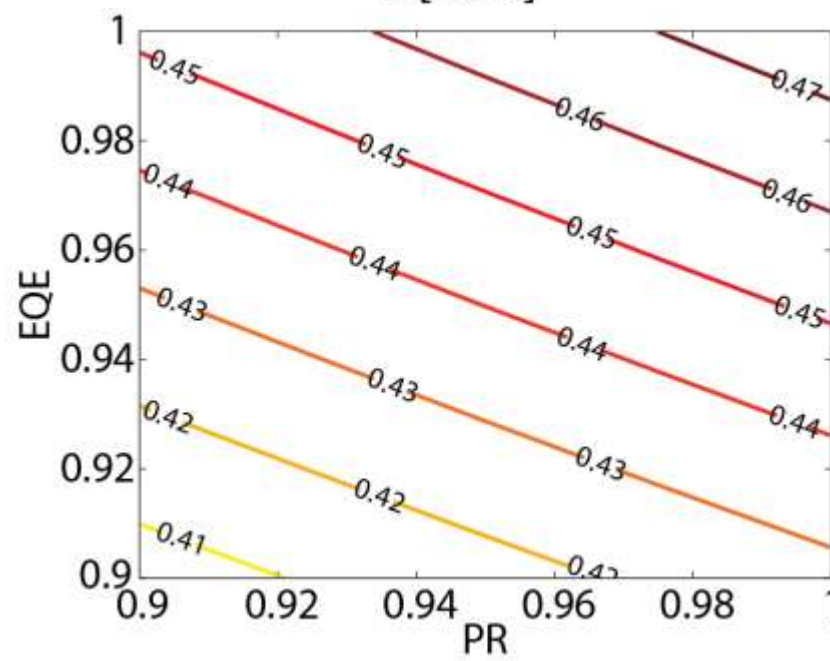
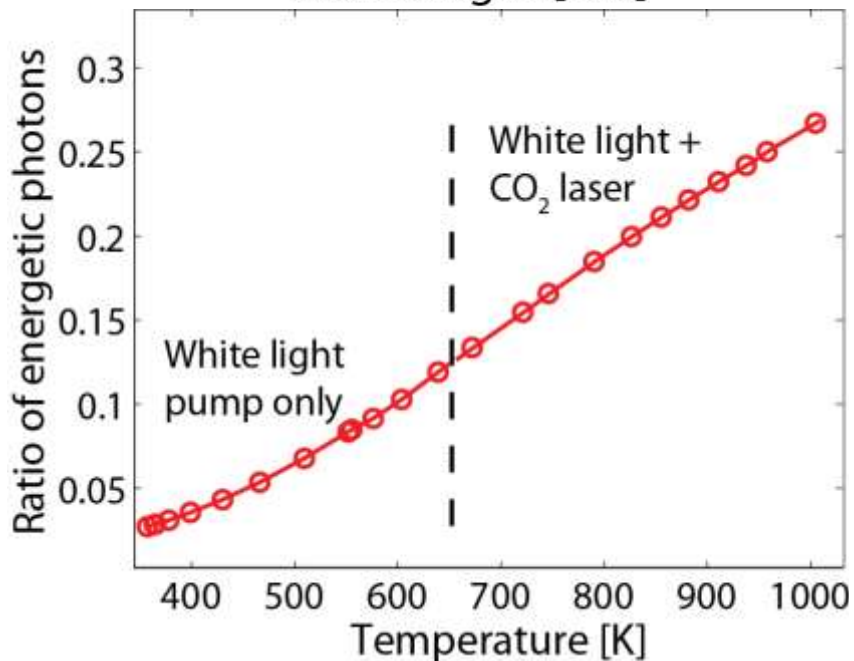
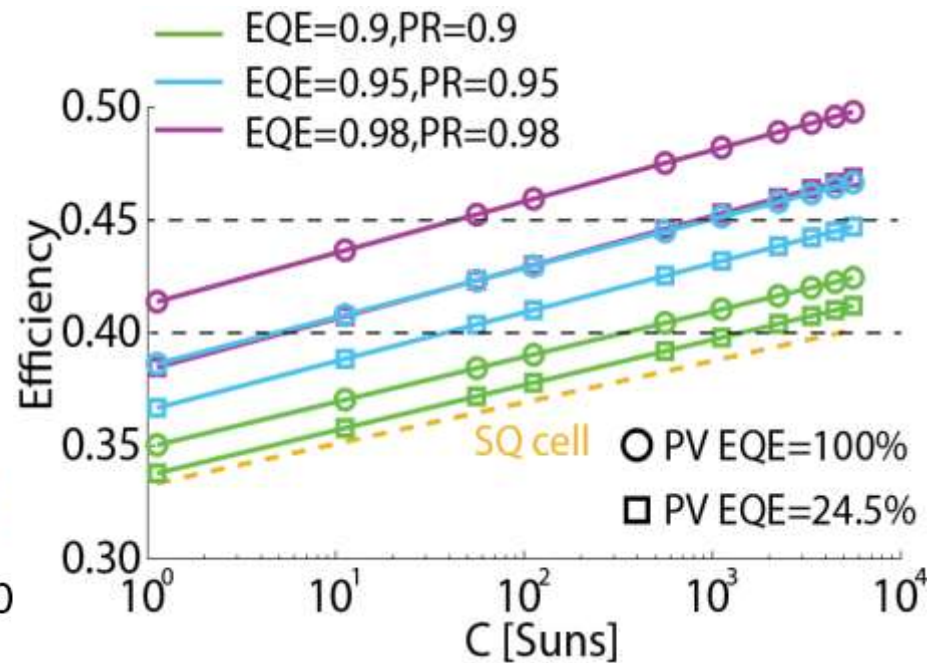
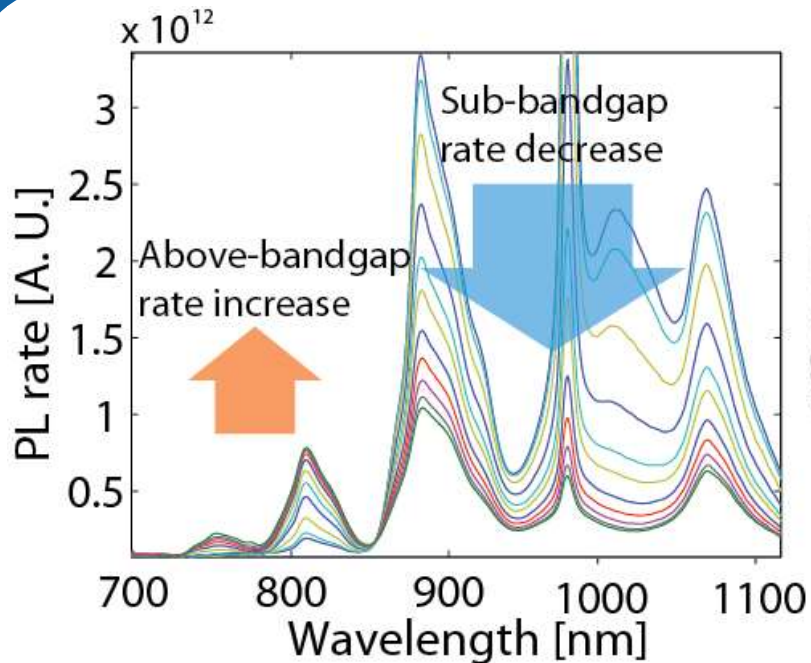
- Full Solar Absorption
- Thermal Insulation
- Optical design
- Mirrors Reflectivity



- Absorber-PV spectral Matching
- Absorber EQE  
(External Quantum Efficiency)



# TEPL Solar Converter: Practical model



Sunlight

Vacuum

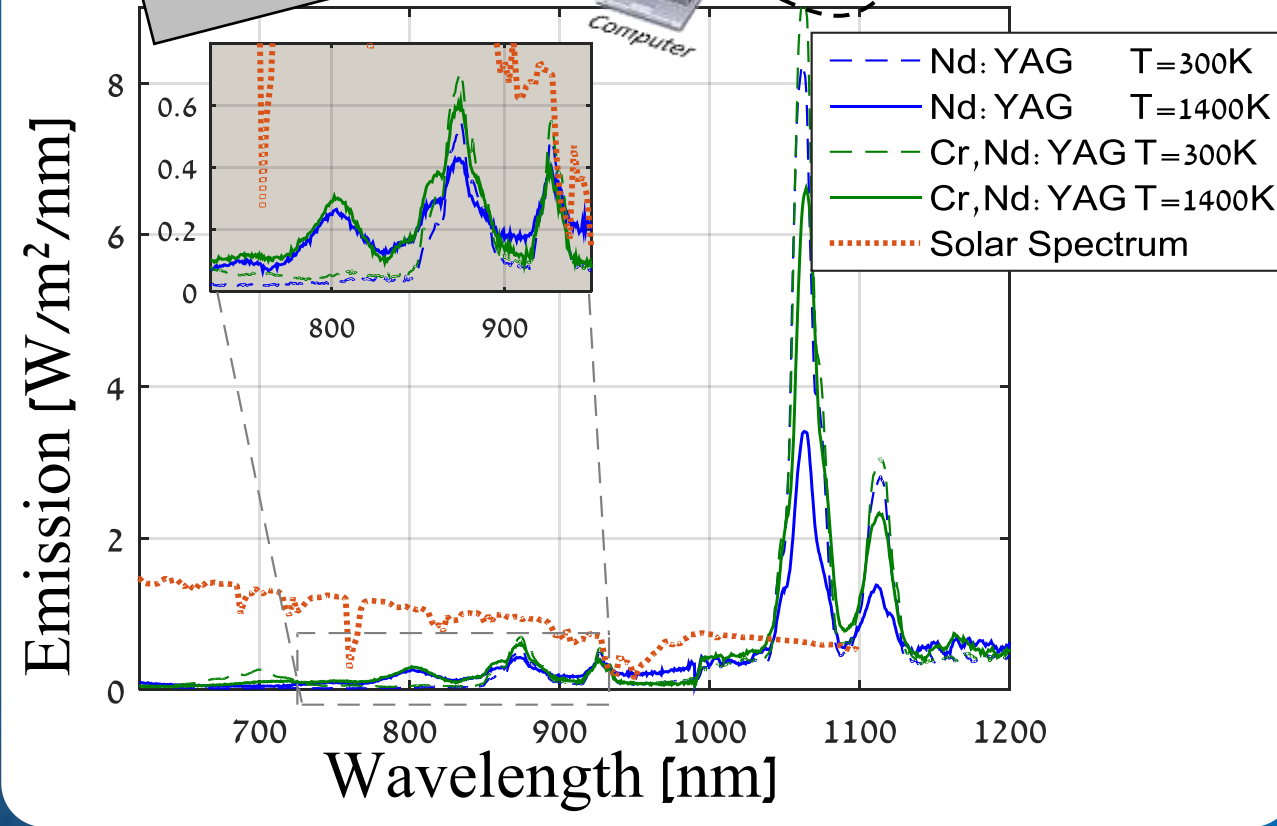
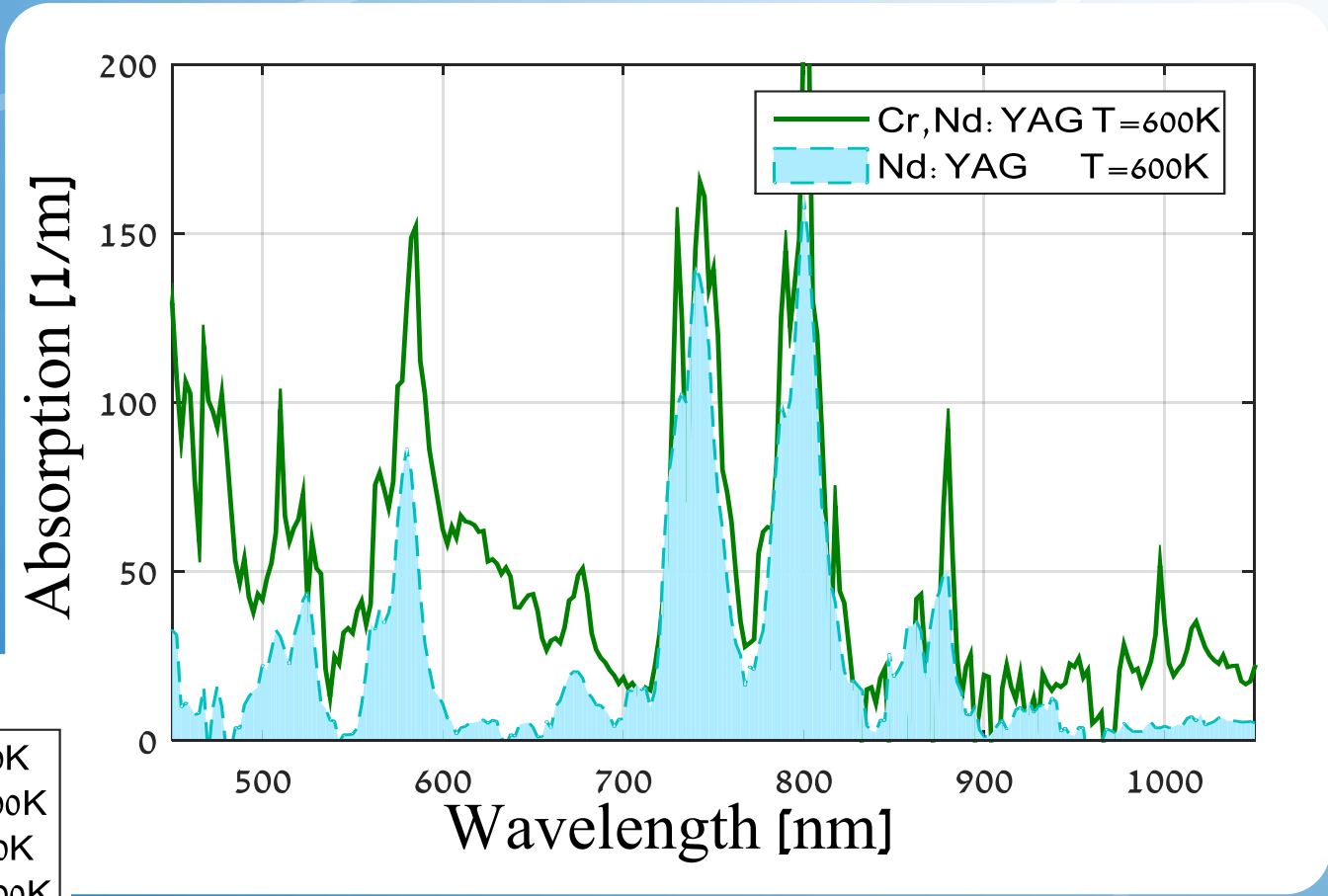
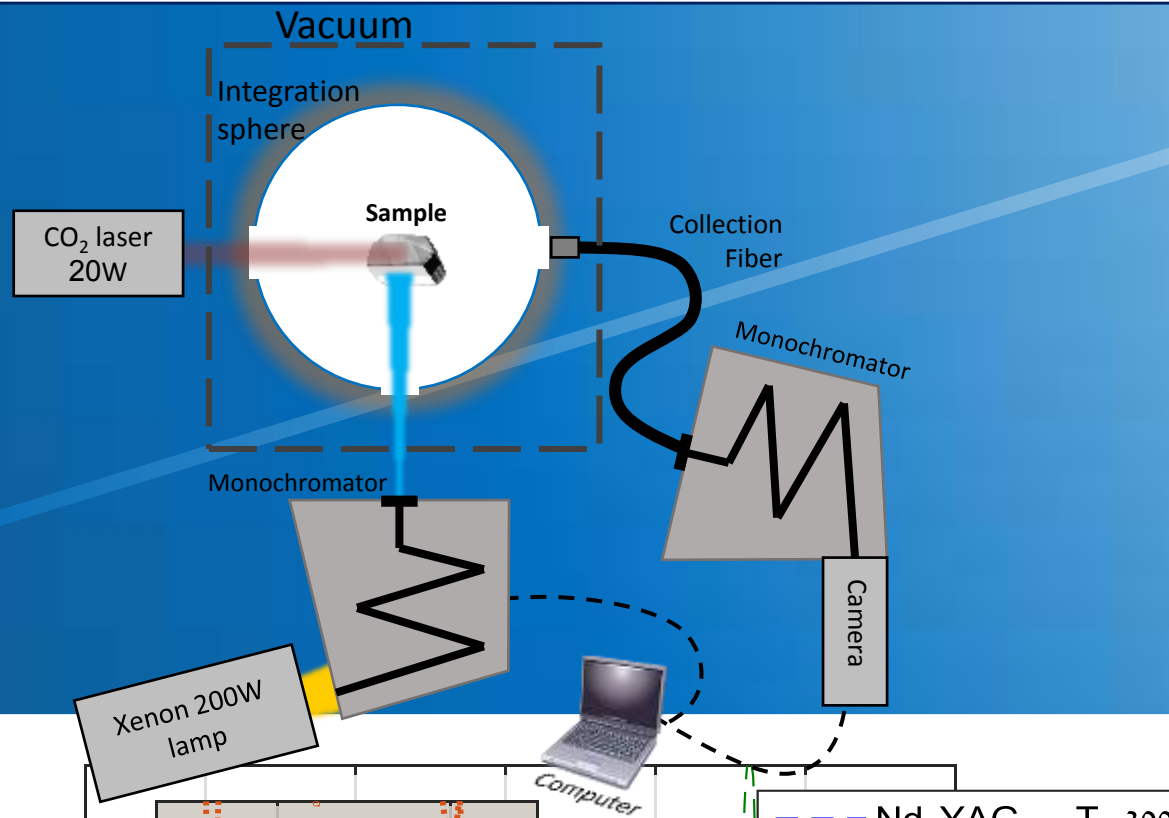
PV & Back Reflector

Mirror

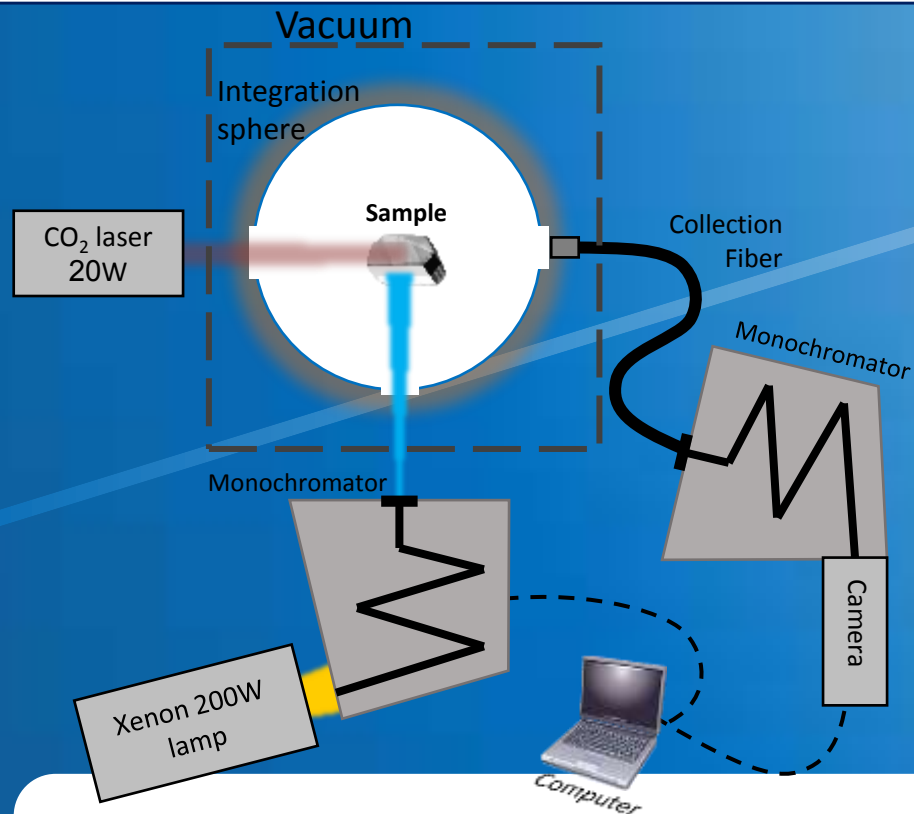
Absorber



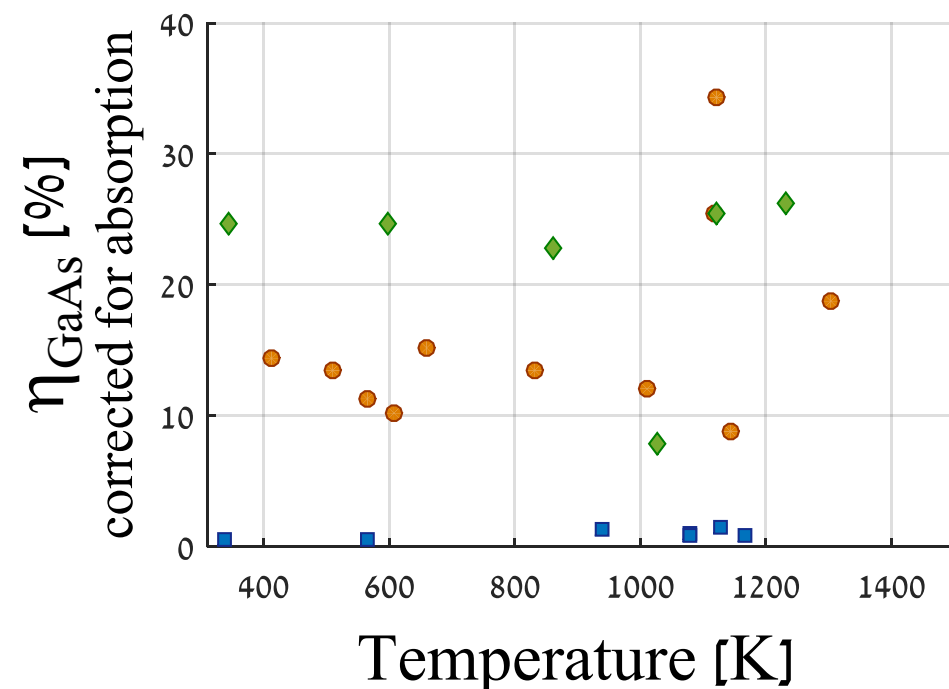
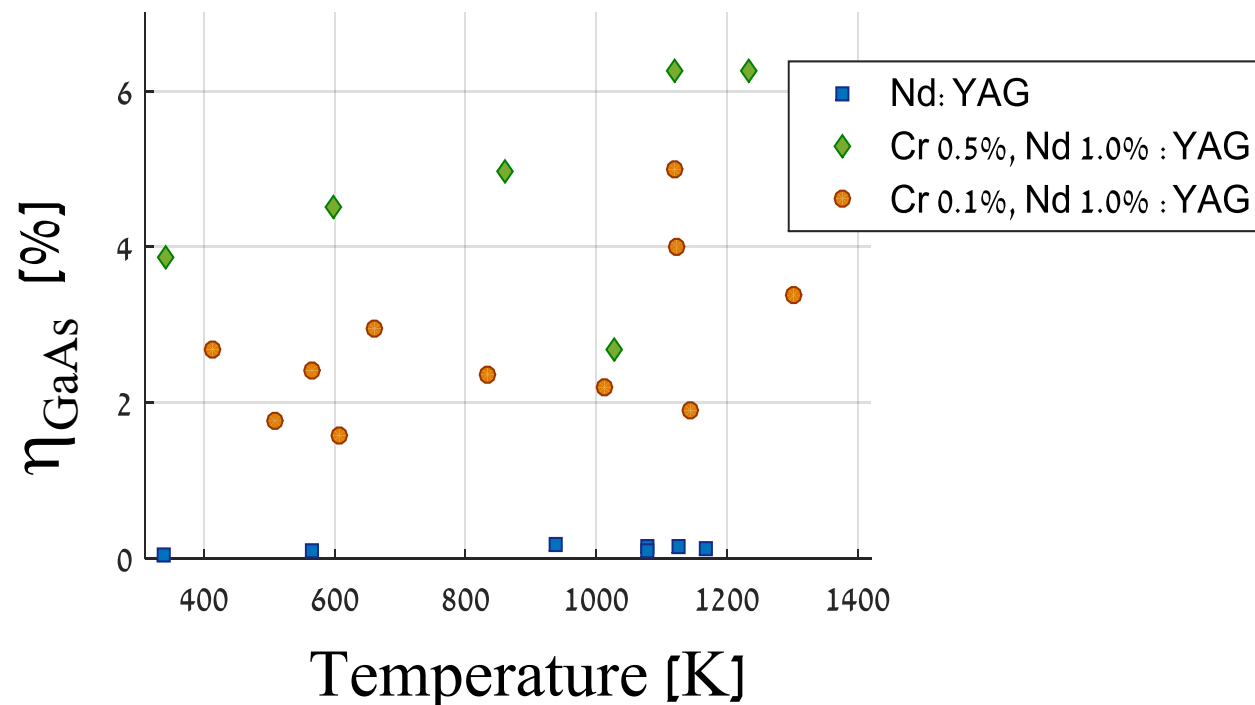
# TEPL material characterization



# TEPL material characterization



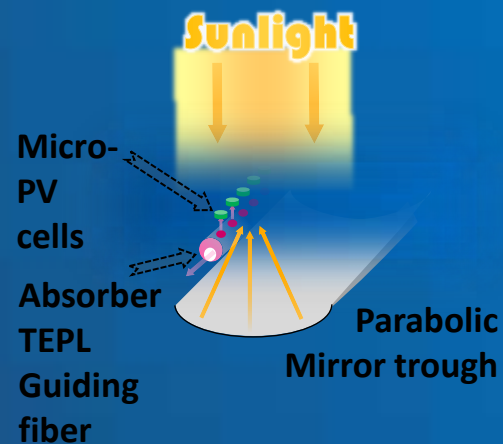
Modeled total (ideal) GaAs PV power output out of the total sun power / total absorbed power



# To Conclude:

- We describe a TEPL conversion device and the considered parameters
- We modeled a practical model estimating over 43% conversion efficiency is in reach

- TEPL materials Absorption and emission characterization

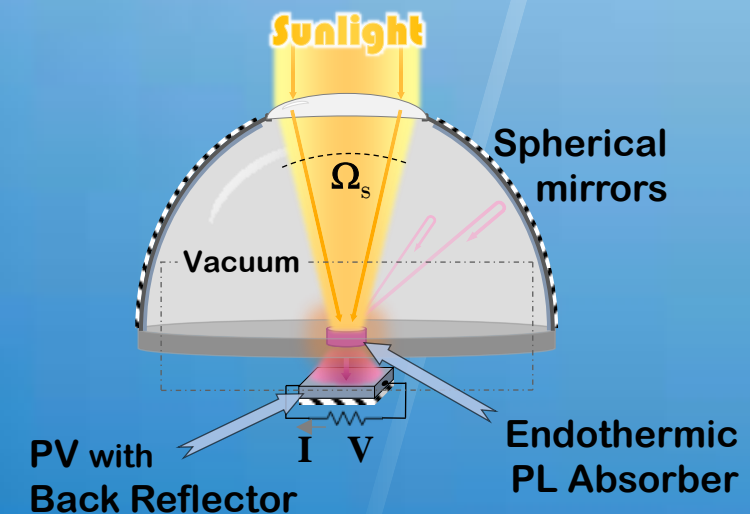
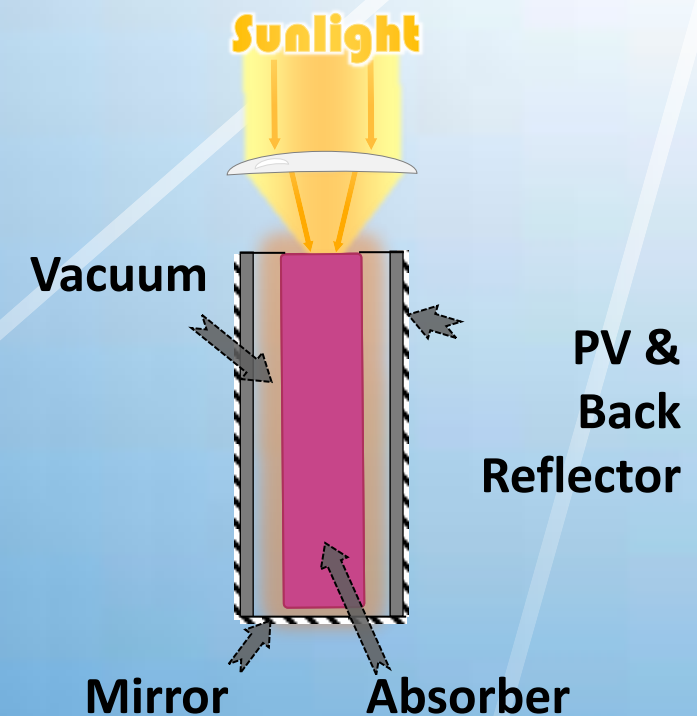


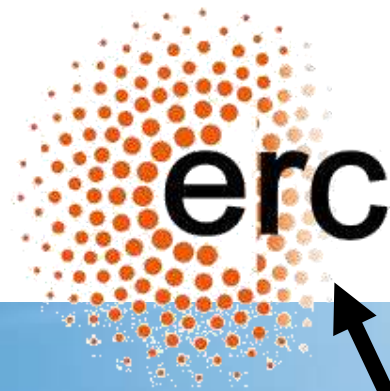
- Cr,Nd,Yb:glass - Int. efficiency up to 30%

- Cr,Nd:YAG

Ext. efficiency up to 6%

Ext. efficiency ~25% absorption corrected





Thanks also to the generous contributors from

# Thanks!

